## NSN 5961-01-249-6215

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-249-6215 **Inclosure Material:** Ceramic **Overall Length:** Between 0.660 inches and 0.830 inches **Terminal Length:** 0.125 inches **Overall Height:** Between 0.105 inches and 0.210 inches **Overall Width:** Between 0.220 inches and 0.310 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 20.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 2.00 amperes source cutoff current of standard range all transistor **Power Rating Per Characteristic:** 1.75 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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